Unit: mm

TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC5352

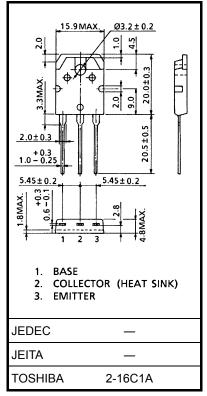
Switching Regulator and High-Voltage Switching Applications

High-Speed DC-DC Converter Applications

- Excellent switching times: t_r = 0.5 μs (max), t_f = 0.3 μs (max) (IC = 4 A)
- High breakdown voltage: $V_{CEO} = 400 \text{ V}$

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	600	V	
Collector-emitter voltage		V _{CEO}	400	V	
Emitter-base voltage		V _{EBO}	7	٧	
Collector current	DC	IC	10	Α	
	Pulse	I _{CP}	15		
Base current		ΙB	5	Α	
Collector power dissipation		Pc	80	W	
(Tc = 25°C)		FC	60	VV	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	



Weight: 4.7 g (typ.)

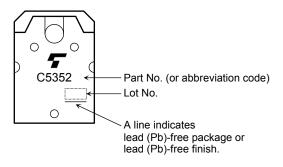
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

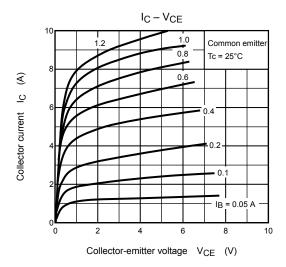
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

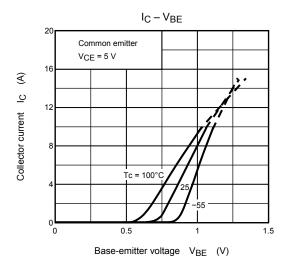
Electrical Characteristics (Tc = 25°C)

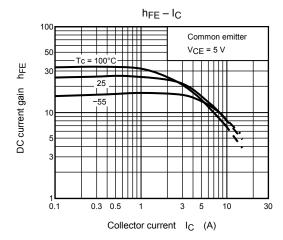
Characteristics Symbol Test Condition		Test Condition	Min	Тур.	Max	Unit	
Collector cut-off of	current	I _{CBO}	V _{CB} = 480 V, I _E = 0	_	_	100	μΑ
Emitter cut-off cu	rrent	I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	1	mA
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _E = 0	600	_	_	V
Collector-emitter	breakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	400	_	_	V
DC current gain		h _{FE}	V _{CE} = 5 V, I _C = 1 A	20	_	_	
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 4 A, I _B = 0.5 A	_	_	1.0	V
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 4 A, I _B = 0.5 A	_	_	1.3	V
Switching time	Rise time	t _r	V _{CC} ≈ 200 V	_	_	0.5	
	Storage time	t _{stg}	20 µs Ic ↓ S Octobro Output	I	_	2.0	μs
	Fall time	t _f	I _{B1} = 0.5 A, I _{B2} = −1 A, duty cycle ≤ 1%	_	_	0.3	

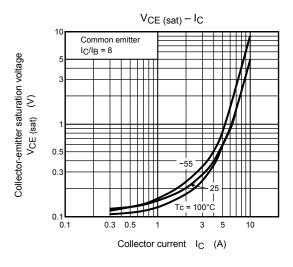
Marking

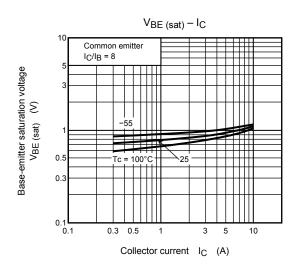


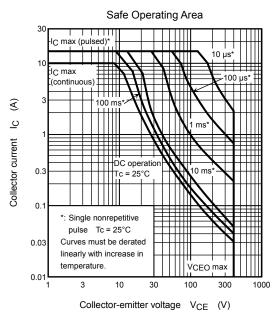












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20070701-EN

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